



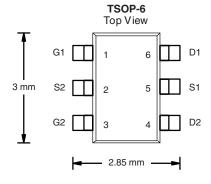
Dual N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)		
30	0.105 at V _{GS} = 10 V	± 2.5		
	0.175 at V _{GS} = 4.5 V	± 2.0		

FEATURES

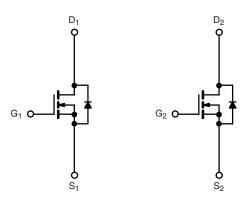
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFETs
- Compliant to RoHS Directive 2002/95/EC





Ordering Information: Si3948DV-T1-E3 (Lead (Pb)-free)

Si3948DV-T1-GE3 (Lead (Pb)-free and Halogen-free)



N-Channel MOSFET

N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted					
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	30	V	
Gate-Source Voltage		V _{GS}	± 20		
Continuous Drain Current (T,I = 150 °C) ^{a, b}	T _A = 25 °C	I _D	± 2.5	A	
Continuous Drain Current (1 _J = 150 °C)	T _A = 70 °C		± 2.0		
Pulsed Drain Current (10 µs Pulse Width)		I _{DM}	± 8	A	
Continuous Source Current (Diode Conduction) ^{a, b}		I _S	1.05		
2 2	T _A = 25 °C	- P _D	1.15	- W	
Maximum Power Dissipation ^{a, b}	T _A = 70 °C] ' ^D	0.73		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Manifestor Locality Assistant	t ≤ 5 s	R _{thJA}	93	110	
Maximum Junction-to-Ambient ^a	Steady State	¹ ¹thJA	130	150	°C/W
Maximum Junction-to-Lead	Steady State	R _{thJL}	75	90	

Notes:

a. Surface Mounted on FR4 board.

 $b.\ t \leq 5\ s.$

Si3948DV

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SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1.0			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zava Cata Valtana Duain Commant		V _{DS} = 24 V, V _{GS} = 0 V			1	μА	
Zero Gate Voltage Drain Current	IDSS	V_{DS} = 24 V, V_{GS} = 0 V, T_J = 55 °C			5		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	5			Α	
	В	V _{GS} = 10 V, I _D = 2.5 A	0.085 0.10		0.105		
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 2.0 \text{ A}$		0.140	0.175	Ω	
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 10 \text{ V}, I_D = 2.5 \text{ A}$		4.3		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 1.05 A, V _{GS} = 0 V		0.81	1.1	V	
Dynamic ^b							
Total Gate Charge	Q_g			2.1	3.2		
Gate-Source Charge	Q_{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 5.0 \text{ V}, I_{D} = 1.8 \text{ A}$		0.7		nC	
Gate-Drain Charge	Q_{gd}			0.7			
Turn-On Delay Time	t _{d(on)}			7	11		
Rise Time	t _r	$V_{DD} = 15 \text{ V}, R_{L} = 15 \Omega$		9	14	1	
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 1 A, V_{GEN} = 10 V, R_G = 6 Ω		13	20	ns	
Fall Time	t _f			5	8]	
Source-Drain Reverse Recovery Time	t _{rr}	$I_F = 1.05 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$		35	60		

Notes:

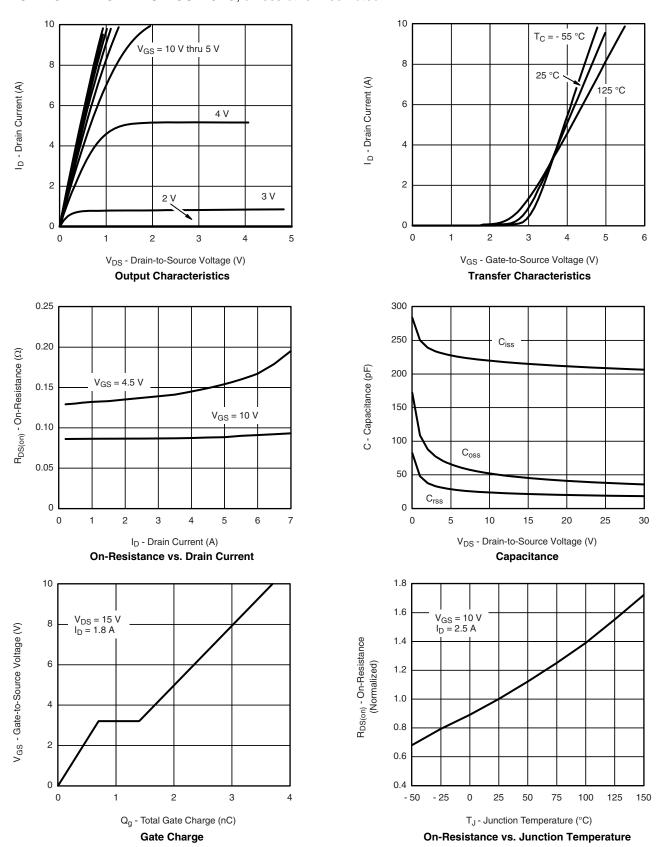
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$

b. Guaranteed by design, not subject to production testing.



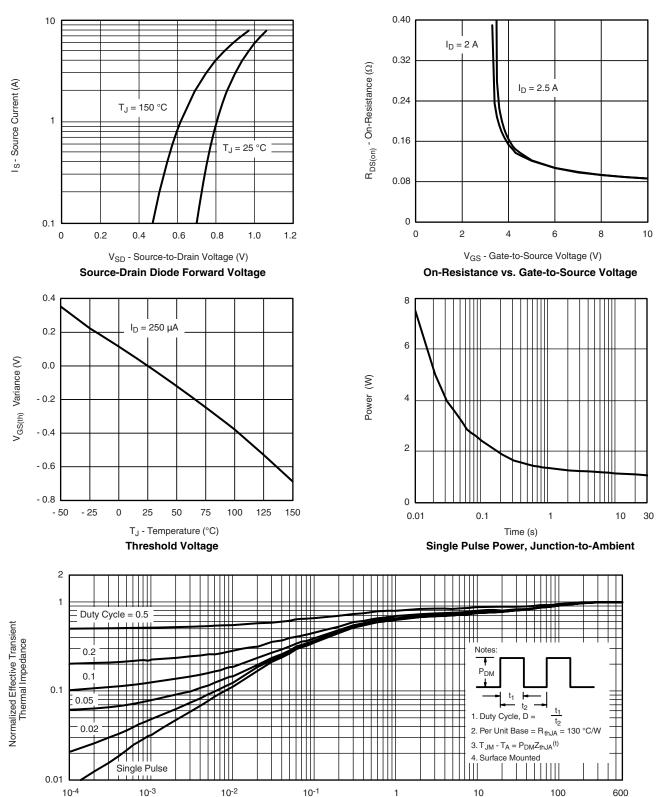
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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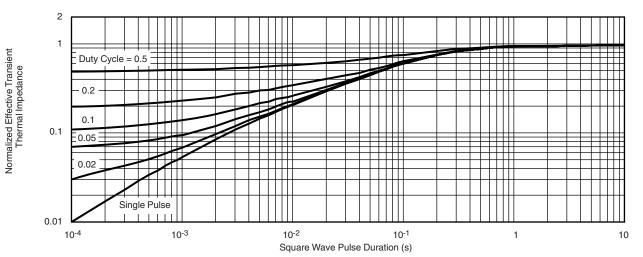
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Normalized Thermal Transient Impedance, Junction-to-Foot

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